(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property
Organization
International Bureau



(43) International Publication Date 21 October 2004 (21.10.2004)

PCT

(10) International Publication Number WO 2004/090996 A1

(51) International Patent Classification⁷: H01L 31/115, 31/119, 29/786, 27/14, 27/148, G01T 1/24, G09G 3/00

(21) International Application Number:

PCT/KR2004/000718

(22) International Filing Date: 30 March 2004 (30.03.2004)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data: 10-2003-0021629

7 April 2003 (07.04.2003) KI

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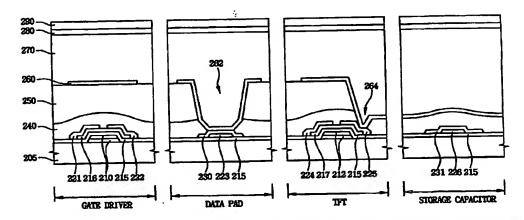
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- (81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, BC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SB, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.
- (84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW). Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:

with international search report

[Continued on next page]

(54) Title: ARRAY PANEL FOR A DIGITAL X-RAY DETECTOR AND METHOD OF MANUFACTURING THE ARRAY PANEL



(57) Abstract: An array panel for a digital X-ray detector including a gate driver (150) is disclosed. A switching element (TFT) is formed in a pixel region defined by gate (110) and data lines (120). A photoelectric cell (130) generates electrons in response to the light supplied from outward. A pixel electrode (260) is formed in the pixel region, and gathers electrons generated from the photoelectric cell (130). A storage capacitor (C) is connected to the drain electrode (225) and stores the electrons gathered in the pixel electrode (260). A gate driver (150) is electrically connected to an end portion of the gate line (110), and provides a scan signal for driving the switching element (TFT). A data pad (140) is electrically connected to an end portion of the data line (120). The electrons stored in the storage capacitor (C) move to the data pad (140) as the switching element (TFT) is turned on. Therefore, the manufacturing cost is reduced, and the manufacturing process is simplified.